NSN 5961-01-221-2486

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-221-2486
Inclosure Material:
Metal
Overall Length:
1.573 inches
Overall Height:
0.450 inches
Overall Width:
1.050 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
5.00 milliamperes forward current, total rms
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpnp
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0